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# FDN8601 N-Channel PowerTrench<sup>®</sup> MOSFET 100 V, 2.7 A, 109 m $\Omega$

## Features

- Max  $r_{DS(on)}$  = 109 m $\Omega$  at V<sub>GS</sub> = 10 V, I<sub>D</sub> = 1.5 A
- Max  $r_{DS(on)}$  = 175 m $\Omega$  at V<sub>GS</sub> = 6 V, I<sub>D</sub> = 1.2 A
- High performance trench technology for extremely low r<sub>DS(on)</sub>
- High power and current handling capability in a widely used surface mount package
- Fast switching speed
- 100% UIL tested
- RoHS Compliant

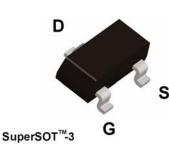


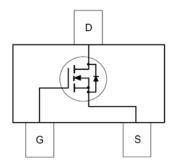
# **General Description**

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench<sup>®</sup> process that has been optimized for  $r_{DS(on)}$ , switching performance and ruggedness.

# Applications

- Primary DC-DC Switch
- Load Switch





## MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter	Ratings	Units		
V <sub>DS</sub>	Drain to Source Voltage		100	V	
V <sub>GS</sub>	Gate to Source Voltage		±20	V	
1	-Continuous	(Note 1a)	2.7	Α	
D	-Pulsed		12		
E <sub>AS</sub>	Single Pulse Avalanche Energy	(Note 3)	13	mJ	
	Power Dissipation	(Note 1a)	1.5	w	
PD	Power Dissipation	(Note 1b)	0.6	vv	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C	

#### **Thermal Characteristics**

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	(Note 1)	75	°C/M
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	80	°C/W

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
8601	FDN8601	SSOT-3	7 "	8 mm	3000 units

Тур	Max	Units	
		V	
68		mV/°C	
	1	μA	
	±100	nA	
3.0	4.0	V	
-8		mV/°C	
85.4	109		
117	175	mΩ	
143	183	_	
8		S	
156	210	pF	
47	65	pF	
2.7	5	pF	
1.0		Ω	

FDN8601 N-Channel PowerTrench<sup>®</sup> MOSFET

BV <sub>DSS</sub>	Drain to Source Breakdown Voltage	I <sub>D</sub> = 250 μA, V <sub>GS</sub> = 0 V	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 $\mu$ A, referenced to 25 °C		68		mV/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 80 V, V <sub>GS</sub> = 0 V			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±100	nA
On Cha	racteristics (Note 2)				-	
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 250 μA	2.0	3.0	4.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D$ = 250 µA, referenced to 25 °C		-8	-	mV/°C
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 1.5 A		85.4	109	
r <sub>DS(on)</sub>	Static Drain to Source On Resistance	V <sub>GS</sub> = 6 V, I <sub>D</sub> = 1.2 A		117	175	mΩ
		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 1.5 A, T <sub>J</sub> = 125 °C		143	183	
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.5 A		8		S
Dynami	c Characteristics			-		
C <sub>iss</sub>	Input Capacitance			156	210	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 0 V, f = 1 MHz		47	65	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			2.7	5	pF
R <sub>g</sub>	Gate Resistance			1.0		Ω
Switchi	ng Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time			4.3	10	ns
t <sub>r</sub>	Rise Time	V <sub>DD</sub> = 50 V, I <sub>D</sub> = 1.5 A,		1.3	10	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{GS}$ = 10 V, $R_{GEN}$ = 6 $\Omega$		7.8	16	ns
t <sub>f</sub>	Fall Time			3.4	10	ns
Qg	Total Gate Charge	$V_{GS} = 0 V$ to 10 V		3	5	nC
Qg	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V V_{DD} = 50 V,$		1.8	3	nC
Q <sub>gs</sub>	Gate to Source Gate Charge	I <sub>D</sub> = 1.5 A		0.9		nC
-						

**Test Conditions** 

Min

## **Drain-Source Diode Characteristics**

Gate to Drain "Miller" Charge

Electrical Characteristics T<sub>J</sub> = 25 °C unless otherwise noted

Parameter

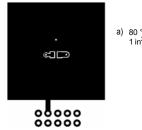
V <sub>SD</sub>	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 1.5 A$ (Note 2)	0.81	1.3	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 1.5 A, di/dt = 100 A/μs		46	ns
Q <sub>rr</sub>	Reverse Recovery Charge	$F = 1.5 \text{ A}, \text{ u/ut} = 100 \text{ A/} \mu \text{s}$	15	27	nC

Q<sub>qd</sub>

Symbol

**Off Characteristics** 

Notes: 1.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.

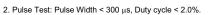


a) 80 °C/W when mounted on a 1 in<sup>2</sup> pad of 2 oz copper



b) 180 °C/W when mounted on a minimum pad.

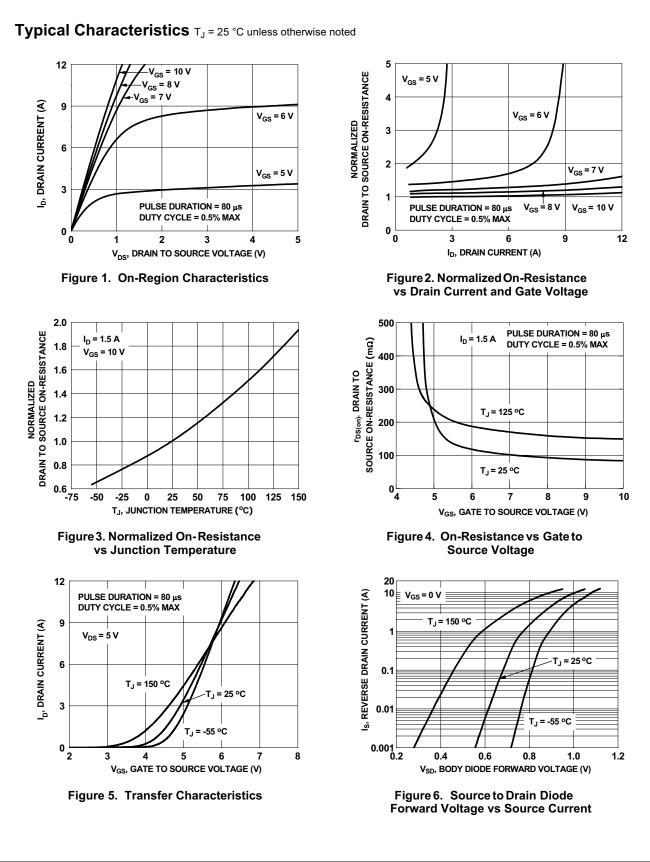
0.8



3. Starting T<sub>J</sub> = 25 °C; N-ch: L = 3 mH, I<sub>AS</sub> = 3 A, V<sub>DD</sub> = 100 V, V<sub>GS</sub> = 10 V.

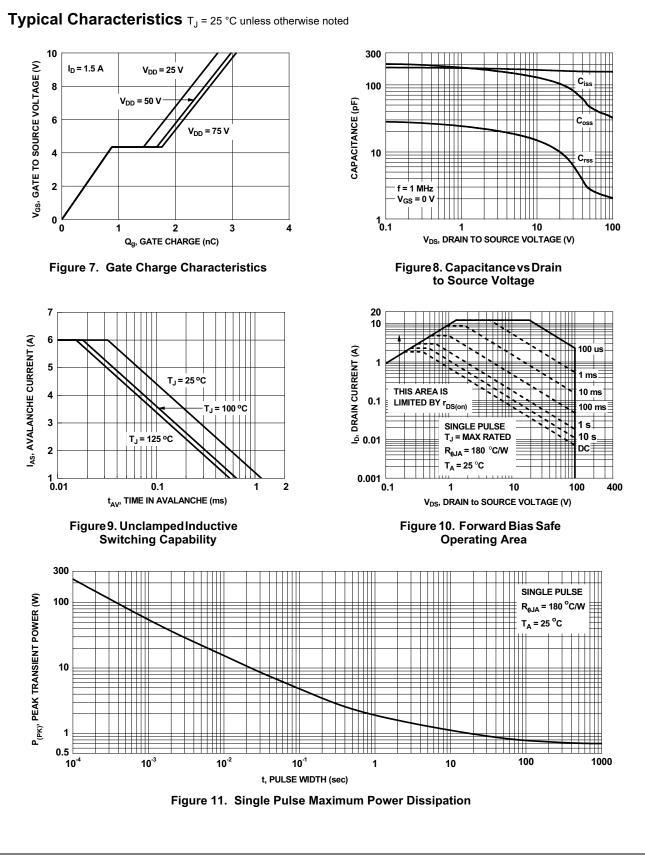
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nC



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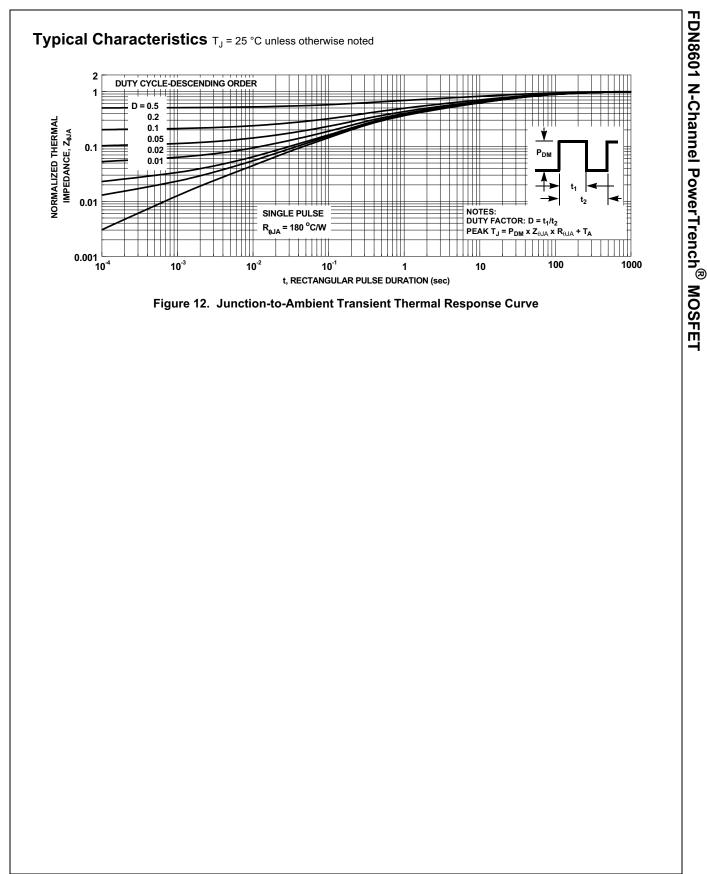
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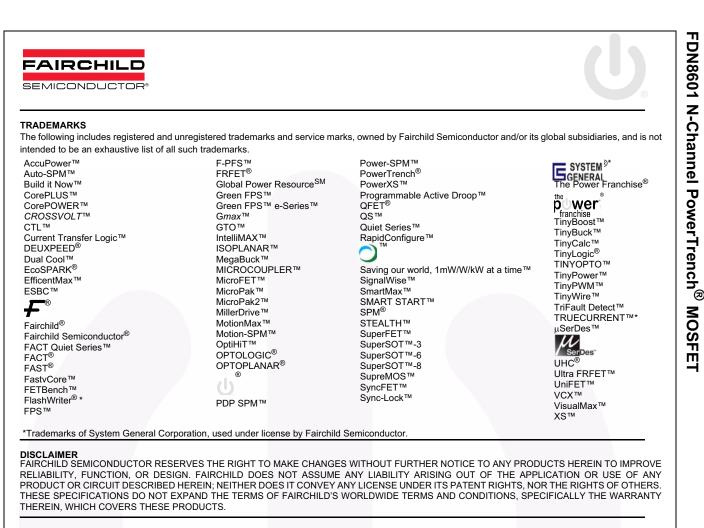


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FDN8601 N-Channel PowerTrench<sup>®</sup> MOSFET





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No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
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